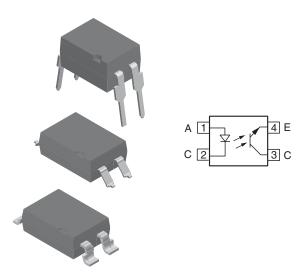


# Optocoupler, Phototransistor Output, High Reliability, 5300 V<sub>RMS</sub>



### **DESCRIPTION**

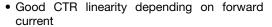
The SFH610A and SFH6106 feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 or SMD package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

The couplers are end-stackable with 2.54 mm spacing.

Creepage and clearance distances of > 8.0 mm are achieved with option 6 and option 8. This version complies with IEC 60950 (DIN VDE 0805) for reinforced insulation up to an operation voltage of 400  $V_{RMS}$  or DC. Specifications subject to change.

#### **FEATURES**





- Isolation test voltage, 5300 V<sub>RMS</sub>
- High collector emitter voltage, V<sub>CFO</sub> = 70 V
- Low saturation voltage
- · Fast switching times
- Low CTR degradation
- Temperature stable
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- High common mode interference immunity
- Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912"><u>www.vishav.com/doc?99912</u></a>

#### AGENCY APPROVALS

- UL1577, file no. E52744 system code H or J, double protection
- DIN EN 60747-5-5 (VDE 0884) available with option 1
- BSI IEC 60950; IEC 60065
- CSA 93751

ORDERING INFORMATION		
S F H 6 1 0 x - # X 0 # # T  PART NUMBER CTR PACKAGE OPTION TAPE AND REEL	7.62 mm Option 7	Option 6  10.16 mm  Option 8
	> 0.7 mm	9.27 mm

AGENCY CERTIFIED/PACKAGE		CTR (%)							
UL, BSI, CSA	40 to 80	63 to 125	100 to 200	160 to 320	250 to 500				
DIP-4	SFH610A-1	SFH610A-2	SFH610A-3	SFH610A-4	SFH610A-5				
DIP-4, 400 mil	-	SFH610A-2X006	SFH610A-3X006	-	-				
SMD-4	SFH6106-1T	SFH6106-2T	SFH6106-3T	SFH6106-4T	SFH6106-5T				
SMD-4, option 7	-	-	SFH610A-3X007T	-	-				
SMD-4, 400 mil, option 8	-	-	-	SFH610A-4X008T	-				
VDE, UL, BSI, CSA (option 1)	40 to 80	63 to 125	100 to 200	160 to 320	250 to 500				
DIP-4	SFH610A-1X001	SFH610A-2X001	SFH610A-3X001	SFH610A-4X001	-				
DIP-4, 400 mil	SFH610A-1X016	-	SFH610A-3X016	SFH610A-4X016	-				
SMD-4	SFH6106-1X001T	SFH6106-2X001T	SFH6106-3X001T	SFH6106-4X001T	-				
SMD-4, 400 mil, option 8	SFH610A-1X018T	-	-	-	-				

#### Note

• For additional information on the available options refer to option information



ABSOLUTE MAXIMUM RATINGS (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT			
INPUT							
Reverse voltage		$V_{R}$	6	V			
DC forward current		I <sub>F</sub>	60	mA			
Surge forward current	t ≤ 10 µs	I <sub>FSM</sub>	2.5	Α			
Power dissipation		P <sub>diss</sub>	100	mW			
OUTPUT							
Collector emitter voltage		$V_{CEO}$	70	V			
Emitter collector voltage		$V_{ECO}$	7	V			
Collector current		Ι <sub>C</sub>	50	mA			
Collector current	t <sub>p</sub> ≤ 1.0 ms	Ι <sub>C</sub>	100	mA			
Power dissipation		P <sub>diss</sub>	150	mW			
COUPLER							
Storage temperature range		T <sub>stg</sub>	-55 to +150	°C			
Ambient temperature range		T <sub>amb</sub>	-55 to +100	°C			
Soldering temperature (1)	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm	T <sub>sld</sub>	260	°C			

#### **Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
  implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
  maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT		1					
Forward voltage	I <sub>F</sub> = 60 mA		$V_{F}$	-	1.25	1.65	V
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>	-	0.01	10	μΑ
Capacitance	V <sub>R</sub> = 0 V, f = 1 MHz		Co	-	13	-	pF
Thermal resistance			R <sub>thja</sub>	-	750	-	K/W
OUTPUT		•					
Collector emitter capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz		C <sub>CE</sub>	-	5.2	-	pF
Thermal resistance			R <sub>thja</sub>	-	500	-	K/W
		SFH610A-1	I <sub>CEO</sub>	-	2	50	nA
		SFH6106-1	I <sub>CEO</sub>	-	2	50	nA
		SFH610A-2	I <sub>CEO</sub>	-	2	50	nA
		SFH6106-2	I <sub>CEO</sub>	-	2	50	nA
Collector amittar laskage current	V - 10 V	SFH610A-3	I <sub>CEO</sub>	-	5	100	nA
Collector emitter leakage current	$V_{CE} = 10 \text{ V}$	SFH6106-3	I <sub>CEO</sub>	-	5	100	nA
		SFH610A-4	I <sub>CEO</sub>	-	5	100	nA
		SFH6106-4	I <sub>CEO</sub>	-	5	100	nA
		SFH610A-5	I <sub>CEO</sub>	-	5	100	nA
		SFH6106-5	I <sub>CEO</sub>	-	5	100	nA
COUPLER							
Collector emitter saturation voltage	$I_F = 10 \text{ mA}, I_C = 2.5 \text{ mA}$		V <sub>CEsat</sub>	-	0.25	0.4	V
Coupling capacitance	f = 1 MHz		C <sub>C</sub>	-	0.4	-	рF

#### Note

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.



CURRENT TRANSFER RATIO								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
		SFH610A-1	CTR	40	-	80	%	
		SFH6106-1	CTR	40	-	80	%	
		SFH610A-2	CTR	63	ı	125	%	
		SFH6106-2	CTR	63	-	125	%	
	I <sub>F</sub> = 10 mA, V <sub>CE</sub> = 5.0 V	SFH610A-3	CTR	100	ı	200	%	
	I <sub>F</sub> = 10 IIIA, V <sub>CE</sub> = 5.0 V	SFH6106-3	CTR	100	-	200	%	
		SFH610A-4	CTR	160	-	320	% % % %	
		SFH6106-4	CTR	160	-	320		
I <sub>C</sub> /I <sub>F</sub>		SFH610A-5	CTR	250	-	500		
IC/IF		SFH6106-5	CTR	250	-	500	%	
		SFH610A-1	CTR	13	30	-	%	
		SFH6106-1	CTR	13	30	-	%	
		SFH610A-2	CTR	22	45	-	%	
	1 - 1 m \ \/ - 5 \/	SFH6106-2	CTR	22	45	-	%	
	$I_F = 1 \text{ mA}, V_{CE} = 5 \text{ V}$	SFH610A-3	CTR	34	70	-	%	
		SFH6106-3	CTR	34	70	=	%	
		SFH610A-4	CTR	56	90	=	%	
		SFH6106-4	CTR	56	90	-	%	

SWITCHING CHAR	ACTERISTICS						
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
NON-SATURATED							
Current	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		I <sub>F</sub>	-	10	-	mA
Rise time	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>r</sub>	-	2	-	μs
Fall time	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>f</sub>	-	2	-	μs
Turn-on time	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>on</sub>	-	3	-	μs
Turn-off time	$V_{CC} = 5 \text{ V}, R_L = 75 \Omega$		t <sub>off</sub>	-	2.3	-	μs
Cut-off frequency	V <sub>CC</sub> = 5 V		F <sub>CO</sub>	-	250	-	kHz
SATURATED							
		SFH610A-1	l <sub>F</sub>	lc -	20 -		mA
		SFH6106-1	'F	-		IIIA	
		SFH610A-2	I <sub>F</sub>	-	10	-	mA
Current		SFH6106-2					IIIA
Current		SFH610A-3	1-		10		mA
		SFH6106-3	I <sub>F</sub>	-	10		
		SFH610A-4	1-	=	- 5	_	mA
		SFH6106-4	l <sub>F</sub>	-	3	_	IIIA
SATURATED							
		SFH610A-1	+	_	2		
		SFH6106-1	t <sub>r</sub>	-	2	-	μs
		SFH610A-2	+		3		μs
Rise time		SFH6106-2	t <sub>r</sub>	-		_	
		SFH610A-3	1		3		μs
		SFH6106-3	t <sub>r</sub>	=	3	-	
		SFH610A-4	+				
		SFH6106-4	t <sub>r</sub>	-	4	-	μs



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SWITCHING CHARACTERISTICS							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
		SFH610A-1	t <sub>f</sub>		11	-	
		SFH6106-1		-			μs
		SFH610A-2			14		
Fall time		SFH6106-2		=	14	-	μs
raii ume		SFH610A-3	+	_	14	_	
		SFH6106-3	t <sub>f</sub>	_	14	-	μs
		SFH610A-4	+	_	15		μs
		SFH6106-4	t <sub>f</sub>	_	15	-	
		SFH610A-1	t <sub>on</sub>	-	3	-	
		SFH6106-1					μs
		SFH610A-2		-	4.2	-	μs
Turn-on time		SFH6106-2					
rum-on time		SFH610A-3		_	4.2	-	μs
		SFH6106-3	t <sub>on</sub>	_	4.2		
		SFH610A-4	+	_	6	_	
		SFH6106-4	t <sub>on</sub>	_	0	_	μs
		SFH610A-1	+	_	18		110
		SFH6106-1	t <sub>off</sub>	_	10	-	μs
		SFH610A-2	+	_	23		μs
Turn-off time		SFH6106-2	t <sub>off</sub>	_	23	-	
		SFH610A-3	+		23		
		SFH6106-3	t <sub>off</sub>	=	23	-	μs
		SFH610A-4	+	_	25		ше
		SFH6106-4	t <sub>off</sub>		25	-	μs

#### Note

• All values presented are typical values.

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Climatic classification	According to IEC 68 part 1		55 / 100 / 21	
Comparative tracking index	Insulation group IIIa	CTI	175	
Maximum rated withstanding isolation voltage	According to UL1577, t = 1 min	V <sub>ISO</sub>	4420	V <sub>RMS</sub>
Tested withstanding isolation voltage	According to UL1577, t = 1 s	V <sub>ISO</sub>	5300	V <sub>RMS</sub>
Maximum transient isolation voltage	According to DIN EN 60747-5-5	V <sub>IOTM</sub>	10 000	V
Maximum repetitive peak isolation voltage	According to DIN EN 60747-5-5	V <sub>IORM</sub>	890	V
Isolation resistance	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 25 °C	R <sub>IO</sub>	≥ 10 <sup>12</sup>	Ω
	V <sub>IO</sub> = 500 V, T <sub>amb</sub> = 100 °C	R <sub>IO</sub>	≥ 10 <sup>11</sup>	Ω
Output safety power		P <sub>SO</sub>	400	mW
Input safety current		I <sub>SI</sub>	275	mA
Input safety temperature		T <sub>SI</sub>	175	°C
Creepage distance	DID 4 / CMD 4		≥ 7	mm
Clearance distance	DIP-4 / SMD-4		≥ 7	mm
Creepage distance	DID 4 400 mil / SMD 4 400 mil		≥ 8	mm
Clearance distance	DIP-4, 400 mil / SMD-4, 400 mil		≥ 8	mm
Insulation thickness		DTI	≥ 0.4	mm

### Note

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

### **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

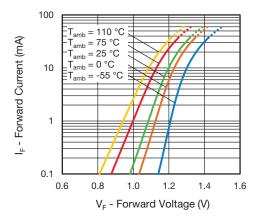


Fig. 1 - Forward Voltage vs. Forward Current

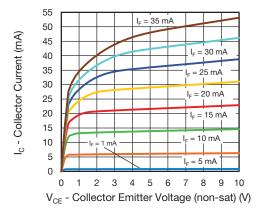


Fig. 2 - Collector Current vs. Collector Emitter Voltage (NS)

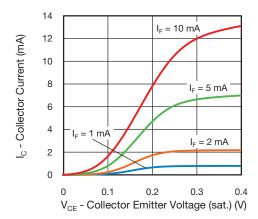


Fig. 3 - Collector Current vs. Collector Emitter Voltage (saturated)

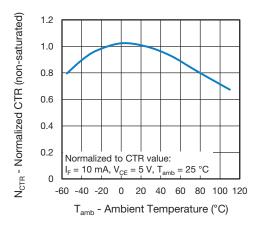


Fig. 4 - Normalized Current Transfer Ratio (non-saturated) vs.

Ambient Temperature

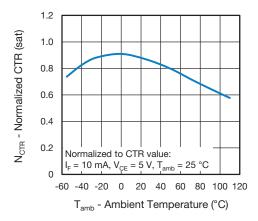


Fig. 5 - Normalized Current Transfer Ratio (saturated) vs.
Ambient Temperature

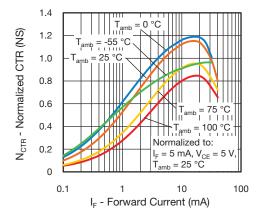


Fig. 6 - Normalized CTR (non-saturated) vs. Forward Current

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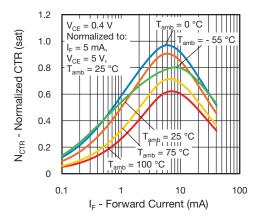


Fig. 7 - Normalized CTR (saturated) vs. Forward Current

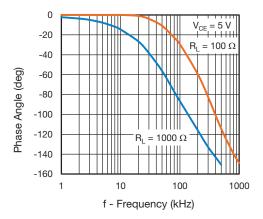


Fig. 8 - Phase Angle vs. Frequency

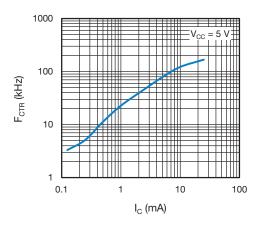


Fig. 9 - CTR Frequency vs. Collector Current

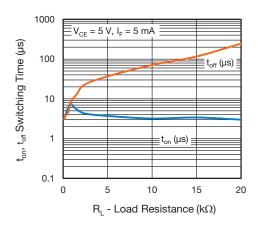


Fig. 10 - Switching Time vs. Load Resistance

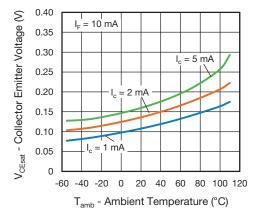
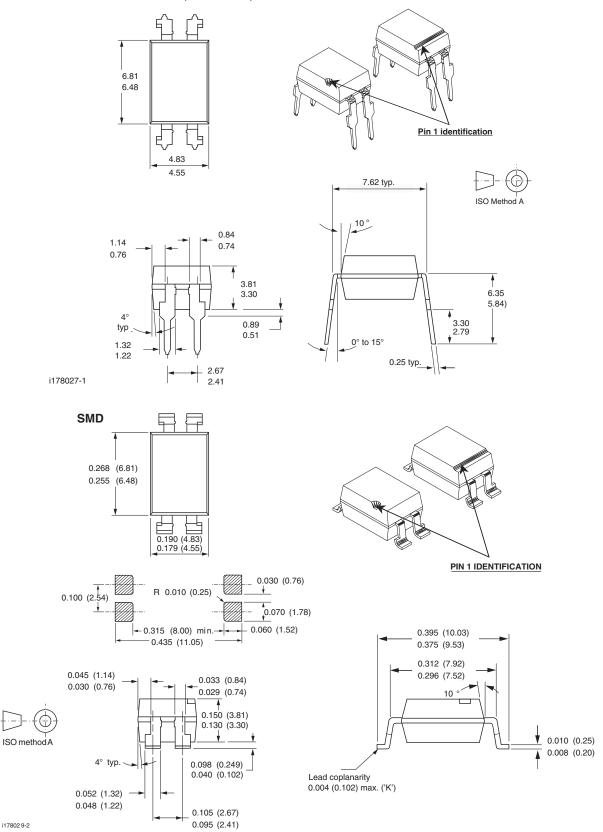


Fig. 11 - Collector Emitter Voltage vs. Ambient Temperature (saturated)

### **PACKAGE DIMENSIONS** in inches (millimeters)

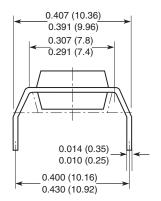


i178029-2

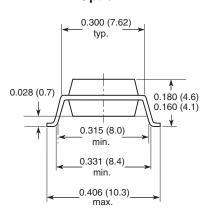




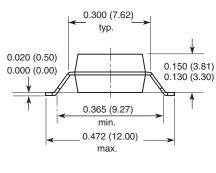
### Option 6



### Option 7



### **Option 8**



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